

# High resolution angle resolved photoemission studies on quasi-particle dynamics in graphite

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We obtained the spectral function of the graphite  $H$  point using high resolution angle resolved photoelectron spectroscopy (ARPES). The extracted width of the spectral function (inverse of the photo-hole lifetime) near the  $H$  point is approximately proportional to the energy as expected from the linearly increasing density of states (DOS) near the Fermi energy. This is well accounted by our electron-phonon coupling theory considering the peculiar electronic DOS near the Fermi level. And we also investigated the temperature dependence of the peak widths both experimentally and theoretically. The upper bound for the electron-phonon coupling parameter is 0.23, nearly the same value as previously reported at the  $K$  point. Our analysis of temperature dependent ARPES data at  $K$  shows that the energy of phonon mode of graphite has much higher energy scale than 125K which is dominant in electron-phonon coupling.

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## I. INTRODUCTION

Fermi liquid theory<sup>1</sup> (FLT) is thought to be one of the most successful theories for describing the behaviors of electrons in solids, especially electrons near the Fermi energy in metals at low temperature. The success of the FLT in metallic systems naturally raises an issue on how far the FLT scheme can be applied to other condensed matter systems. Related to this question, there is a long-standing controversy on whether electrons in graphite, a 2 dimensional semi-metallic system, can be described within the FLT scheme or not. According to FLT, the lifetime of an electron due to electron-electron interactions is inversely proportional to the square of the binding energy. Therefore, measurement of the lifetime as a function of the binding energy of an electron would be a direct test of the validity of FLT in graphite.

Experimental results do not seem to show evidence for Fermi liquid behavior of electrons in graphite<sup>2</sup>. In fact, the inverse lifetime measured by 2 photon photoemission experiments (2PPE) conducted on natural single crystal graphite and highly oriented pyrolytic graphite (HOPG) appears to increase linearly as a function of the binding energy<sup>3</sup>. The observed peculiar behavior in the energy dependence of the inverse lifetime was discussed in terms of the peculiar dispersion of plasmon<sup>2</sup> or electron-electron interaction in combination with the band structure of graphite<sup>4,5</sup>.

However, electron-phonon coupling (EPC), one of the most fundamental interactions in solids, has not been considered in the discussion. On the theoretical side, very little work can be found on the EPC in semi-metals even though it has been well developed and widely studied in metallic systems<sup>6</sup>. Only very recently has some theoretical models for graphene appeared<sup>7,8,9</sup>. On the experimental side, electron lifetime was measured only for the energies larger than the maximum phonon energy of graphite ( $\sim 200$  meV)<sup>10,11,12</sup> in the 2PPE experiments<sup>2,3</sup>. Therefore, to address the lifetime issue due to EPC in graphite, one may need two requirements. First, the experimental data must show the lifetime of quasi-particles sufficiently close to the Fermi energy, less than the maximum phonon energy of graphite. Second, a proper model that considers the electron-phonon interaction contribution to the quasi-particle decay should be developed. In regards to the second point, models developed for metals have been used in the analysis of angle resolved photoemission (ARPES) data on graphite due to the lack of theoretical EPC models for semi-metals<sup>13</sup>.

To address the issue of the quasi-particle dynamics and EPC in graphite, we performed high resolution ARPES experiments on high quality natural single crystal and developed a theoretical model that considers linear density of states (DOS) near the Fermi energy<sup>14</sup>. Our previous work was performed near the  $K$ -point and showed a relatively small EPC constant  $\lambda = 0.20$ . To extend our

previous we have obtained high resolution ARPES data from the  $H$  point to determine if it also has a small EPC constant. In addition, we also performed temperature dependent studies near the  $K$  point. The temperature dependent data is compared with a theoretical model that fully considers the graphite DOS. Properly extracted peak widths are well understood within our EPC model with a linear DOS near the Fermi energy and shows a small EPC constant of less than 0.23.

## II. THEORY

We first consider the theoretical side of the quasi-particle dynamics in graphite. In this section, we discuss possible decay channels for quasi-particles in graphite. First, it will be discussed how the lifetime of quasi-particles in graphite can be affected by EPC. We will formulate the self energy of quasi-particles based on the linear DOS of graphite, for zero temperature in section 1 and for a finite temperature in section 2. The latter is to establish the foundation for estimating the EPC constant through temperature dependent studies. Second, we will discuss other decay channels such as electron-electron scattering, electron-plasmon scattering, and impurity and defect scattering. Through these discussions, we wish to establish that the dominant scattering mechanism for quasi-particles in graphite comes from the EPC.

### A. Electron-phonon coupling in graphite

Electron-phonon interaction theory is an extensively studied subject in condensed matter physics. The importance of its role is high-lighted in the theory for conventional superconductors, i.e., the BCS theory. Even though a general theory should be applicable to any system, specific and more applicable models have been developed for metallic systems. However, a key assumption used for metallic systems, constant DOS near the Fermi level, is not valid for semi-metals and insulators. To the best of our knowledge, EPCs in semi-metals and insulators have not been thoroughly studied theoretically (probably due to lack of interest). With recent developments in graphene/graphite related research<sup>7,8,15</sup>, EPC in semi-metals has become more important. Therefore, we need a model to evaluate the EPC constant in graphite.

To understand the EPC in graphite, one should consider its characteristic band structure near the Fermi level. Fig. 1(a) shows the crystal structure of graphite. Graphite has a layered structure and the stacking order is  $ABAB\dots$ . In each layer, carbon atoms form strong  $\sigma$  bonds produced by  $sp^2$  hybridization while the out-of-plane  $p_z$  orbitals form  $\pi$  bonds. Fig. 1(b) depicts the first Brillouin zone (BZ) and high symmetry points of graphite in reciprocal space. The calculated electronic band dispersion of graphite along the high symmetry

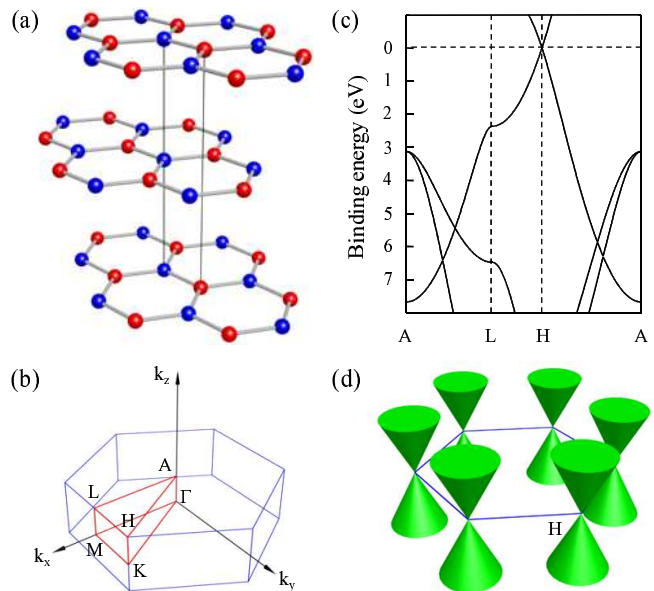


FIG. 1: (a) The structure of graphite. Spheres are carbon atoms. Graphite shows a layered structure, which has a stacking order of  $ABAB\dots$  (b) First Brillouin zone of graphite. The symbols represent high symmetry points. (c) Calculated electronic band structure along  $A$ - $L$ - $H$ - $A$ . (d) Approximated band structure. Each corner of hexagon is  $H$  point and  $z$  direction is energy.

line,  $A$ - $L$ - $H$ - $A$ , is plotted in Fig. 1(c). The band dispersion within  $\pm 1$  eV near the  $H$  point is almost linear. A three dimensional view of the band dispersion is shown in Fig. 1(d). The point at which the two cones meet each other is at the Fermi energy and is called the Dirac point. This band structure yields a DOS which increases linearly with binding energy (linear DOS). Numerous studies of the band structure of graphite can be found both theoretical<sup>16,17,18,19,20</sup> and experimental sides<sup>21,22,23,24,25,26,27,28,29,30,31,32,33,34</sup>.

The electron-phonon coupling theory in graphite should be considered within this characteristic linear DOS. To understand the electron-phonon coupling in graphite, one needs to get the real or imaginary parts of the self energy. If one approaches electron-phonon coupling through the real part of the self energy, one has to confront a task of finding the bare band. The bare band of graphite is not linear and hence much harder to guess in comparison with metallic systems. Even though it was argued that the experimentally measured band structure at  $H$  is linear<sup>33</sup>, our results show that the dispersion is not linear and has some parabolic character near the Fermi energy. Therefore, we chose to use the imaginary part in the analysis. Note that the real part of the self energy can be obtained by Hilbert transforming the imaginary part. Fig. 2(a) shows the Feynman diagram<sup>35</sup> for the lowest order EPC under consideration. Our model considers only this lowest order EPC in this section. One can describe the many-body effects

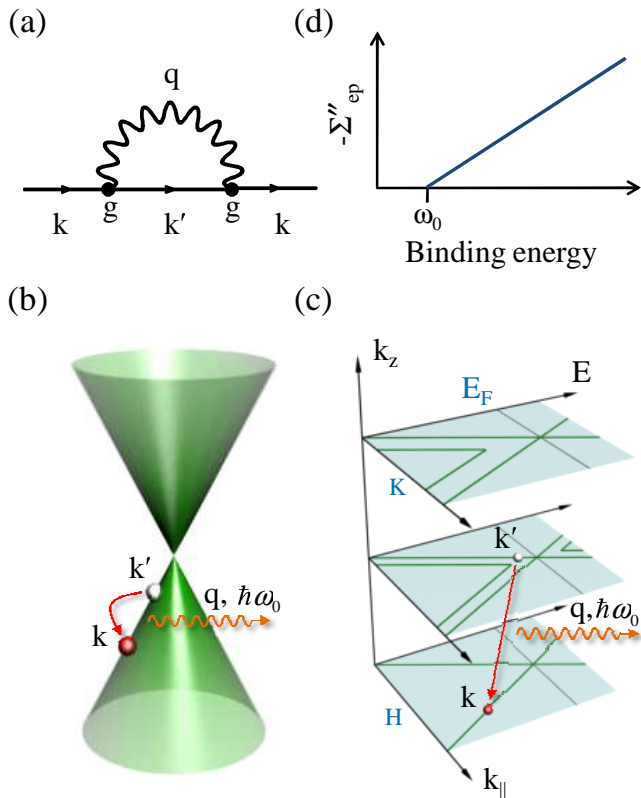


FIG. 2: (a) The lowest order Feynman diagram for EPC.  $g$  is electron phonon coupling constant.  $k$  and  $k'$  are crystal momenta of holes.  $q$  is momentum of phonon. (b) Schematic diagram of the EPC process as shown in panel (a). Photo-hole  $k$  makes a transition to  $k'$  emitting phonon of  $q$ .  $\hbar\omega_0$  is the emitted phonon energy. (c) Schematic diagram for scattering in  $k_z$  direction. (d) The imaginary part of the self energy vs. binding energy predicted by our qualitative theory (see the text).

on quasi-particles using a self energy scheme. The imaginary part of self energy is proportional to the scattering rate of quasi-particle. Here, we present the EPC process for zero ( $T = 0$ ) and finite temperature cases ( $T \neq 0$ ) separately.

### 1. Zero temperature case

The Hamiltonian of EPC interaction can be written as,

$$H_{\text{ep}} = \sum_{i,\sigma,\nu} g_{\nu} c_{k+q,\sigma}^{\dagger} c_{k,\sigma} (b_{q,\nu}^{\dagger} + b_{-q,\nu}) \quad (1)$$

where  $c_{k,\sigma}^{\dagger}$  ( $c_{k,\sigma}$ ) creates (annihilates) an electron with spin  $\sigma$  and momentum  $k$  while  $b_q^{\dagger}$  ( $b_q$ ) creates (annihilates) a phonon  $\nu$  with momentum  $q$ . The scattering amplitude  $g$  is taken to be energy and momentum independent.  $b_{q,\nu}^{\dagger}$  term is for phonon emission process and  $b_{-q,\nu}$  term is for phonon absorption. Then the imaginary

part of the self-energy is defined as a convolution over the density of states:<sup>36</sup>

$$\Sigma''_{\text{ep}}(\omega) = \sum_{\nu} -g_{\nu}^2 \pi (\mathcal{D}(\omega - \omega_{\nu}) [f(\omega_{\nu} - \omega) + b(\omega_{\nu})] + \mathcal{D}(\omega + \omega_{\nu}) [f(\omega_{\nu} + \omega) + b(\omega_{\nu})]) \quad (2)$$

where  $\mathcal{D}$  is the electronic DOS and  $\omega_{\nu}$  is the energy of a phonon  $\nu$ .  $f$  and  $b$  are Fermi-Dirac and Bose-Einstein distributions, respectively. Since the electron-phonon interaction does not alter the spin of a conduction electron, spin index  $\sigma$  is suppressed to consider only one spin direction.

If we assume an Einstein phonon with an energy of  $\omega_0$  and momentum independent coupling amplitude  $g$ , Eqn. (2) becomes

$$\Sigma''_{\text{ep}}(\omega) = -g^2 \pi (\mathcal{D}(\omega - \omega_0) [f(\omega_0 - \omega) + b(\omega_0)] + \mathcal{D}(\omega + \omega_0) [f(\omega_0 + \omega) + b(\omega_0)]) \quad (3)$$

For the zero temperature case, Fermi-Dirac function can be replaced by step function and the Bose factor is zero in Eqn. (3). Then, Eqn. (3) can be written as,

$$\Sigma''_{\text{ep}}(\omega, T = 0) = -g^2 \pi [\mathcal{D}(\omega - \omega_0) \Theta(\omega - \omega_0) + \mathcal{D}(\omega + \omega_0) \Theta(-\omega - \omega_0)] \quad (4)$$

where  $\Theta$  is a step function,  $\Theta(x) = 0(x < 0)$  and  $\Theta(x) = 1(x \geq 0)$ .

We assume a conical band structure with the Fermi energy at the apex of the cone. There is another conical band above the Fermi energy which is unoccupied, and these two conical bands form a Dirac-cone-like band structure as shown in Fig. 2(b). If a photo-hole with momentum  $\mathbf{k}$  (filled circle) is created by a photon as shown in Fig. 2(b), it can be filled by an electron with energy of  $\omega_{k'} = \omega_k - \omega_0$  and momentum  $\mathbf{k}' = \mathbf{k} - \mathbf{q}$  (empty circle) where  $\mathbf{q}$  is the phonon momentum. The scattering rate is proportional to the number of such  $\mathbf{k}'$  states, thus the DOS at  $\omega_k - \omega_0$ . Note that if the binding energy of the photo-hole is smaller than the phonon energy  $\omega_0$ , the scattering cannot occur because there are no electrons with sufficient energy to emit a phonon with energy  $\omega_0$ . Therefore, the imaginary part of self energy of photo-hole as a function of the binding energy is proportional to  $\mathcal{D}(\omega_k - \omega_0)$  and looks like a schematic shown in Fig. 2(d). Note that it is also possible that a phonon may scatter a photo-hole in the  $k_z$  direction as shown in Fig. 2(c). The outcome is not much affected by the  $c$ -axis scattering due to the weak dispersion of the  $\pi$  band along  $k_z$  direction.

Once  $\Sigma''$  is obtained, one can obtain the real part of self energy  $\Sigma'_{\text{ep}}$  by Hilbert transforming  $\Sigma''$ . The electron-phonon coupling parameter,  $\lambda$  is defined as,

$$\lambda = - \left. \frac{\partial \Sigma'_{\text{ep}}(\omega)}{\partial \omega} \right|_{\omega=0} \quad (5)$$

At the  $K$  point, the bonding and anti-bonding bands are split because of the inter-layer interaction of graphite<sup>37</sup>.

Considering the small inter-band scattering of the photo-hole by a phonon between bonding and non-bonding bands at  $K$  point, the above self energy can be extended to the double band case at  $K$ . This double band case was investigated in our previous work<sup>14</sup>.

We also note that  $\Sigma'_{ep}$  is not affected seriously by the detailed shape of  $\Sigma''_{ep}$  near  $\omega = 0$  because  $\Sigma''_{ep}$  increases linearly. This aspect was considered in calculating  $\Sigma''_{ep}$  for  $K$  and  $H$  points<sup>9</sup>. It was argued that  $\Sigma''_{ep}$  is somewhat different at  $K$  and  $H$  because the band structure at  $K$  is parabolic near the Fermi level while that at  $H$  is linear. Meanwhile some difference between  $K$  and  $H$  certainly exists that affects the detailed shape of  $\Sigma''_{ep}$  near the Fermi energy, the effect on the EPC constant  $\lambda$  should be negligible because the contribution comes mostly from the high binding energy side.

## 2. Finite temperature case

We now move onto the finite temperature case. In the case of metals, there is an easy way to extract the EPC constant  $\lambda$  from temperature dependent data through a simple formula<sup>6,38</sup>. The formula is derived under the assumption that the electronic DOS near the Fermi energy is constant, which is not the case for graphite. Here, we investigate the temperature dependence of  $\Sigma''_{ep}$  theoretically to determine if one can easily extract  $\lambda$  from the temperature dependence data. It turns out that a simple formula such as the one for metals can not be formulated. However, we show some possibility of estimating EPCs from the temperature dependent data.

The imaginary part of the self-energy by electron-phonon coupling at finite temperature was shown in Eqn. (3) of the previous section. Note that for the high phonon frequency (for example,  $A'_1$  or  $E_{2g}$  mode in graphite) the Bose factors can be neglected for the temperature range over which we performed our experiments (10K-225K). We consider not only these high energy phonons but also low energy phonons. Unfortunately, the temperature dependence of  $\Sigma''_{ep}$  in Eqn. (7) cannot be reduced to a simple form as the one for a metal<sup>6</sup> and extracting the  $\lambda$  from the temperature dependence of  $\Sigma''_{ep}$  is not a straight forward task. However, one can still obtain information from the temperature dependent data. If the low frequency phonon mode participates in EPC, the temperature dependence of  $\Sigma''_{ep}$  near the Fermi level should be strong while the high frequency phonon modes should contribute little to the temperature dependence. In addition, the Bose factor in Eqn. (3) is not negligible and  $\Sigma''_{ep}$  will show clear difference at different temperature. Therefore, once the  $g$  value is known, one can roughly identify which phonon mode contributes the most to EPC by fitting the temperature dependent data.

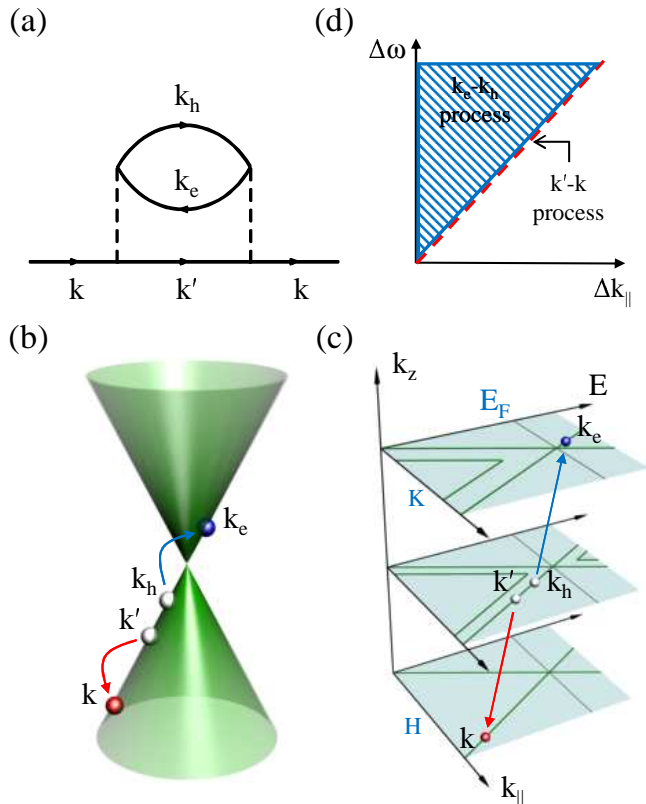


FIG. 3: (a) The Feynman diagram for the lowest order for electron-hole pair creation process. Photo-hole  $k$  makes a transition to a hole  $k'$ , and an electron  $k_e$  and a hole  $k_h$  are created conserving momenta and energy. (b) Schematic diagram for electron-hole pair creation in phase space. (c) Schematic diagram for electron-hole pair creation considering the scattering along  $k_z$  direction. (d) Hatched area represents the possible  $\Delta k$  and  $\Delta\omega$  for electron-hole pair creation. Dashed line represents the possible  $\Delta k$  and  $\Delta\omega$  for photo-hole transition. These two area slightly touch each other at line, therefore there is no available phase space.

## B. Electron-electron interaction in graphite

Electron-electron interactions can also affect the quasi-particle lifetime or the imaginary part of self energy. We consider the lowest order scattering in electron-electron interaction occurring via electron-hole pair creation. The Feynman diagram for this scattering process is shown in Fig. 3(a). When the photo-hole, of crystal momentum is  $\mathbf{k}$ , is created, the hole makes the transition to  $\mathbf{k}'$  by creating another hole,  $\mathbf{k}_h$ , and electron,  $\mathbf{k}_e$ . Fig. 3(b) shows this electron-hole pair creation process in the  $E-k$  phase space. From the figure, one can see that the electron-hole pair creation process is negligible under the linear DOS of graphite near the Fermi energy. Let us consider the available phase space for electron-hole pair creation in Fig. 3(b). If we plot the energy difference ( $\Delta\omega = \omega_{k'} - \omega_k$  where  $\omega_{k'}$  and  $\omega_k$  are the energies of the holes with  $\mathbf{k}'$  and  $\mathbf{k}$ , respectively) as a function of momentum difference ( $\Delta\mathbf{k} = \mathbf{k}' - \mathbf{k}$ ), the possible transitions occupy the area

below the dashed line in Fig 3(d). In a similar way, one can find that electron-hole creation process occupies the hatched area in Fig. 3(d). Photo-hole decay through the electron-hole pair creation can occur only when the two conditions are met, that is, where the phase spaces for the two processes overlap. They overlap only on the dashed line as can be seen in Fig. 3(d). Therefore, the available phase space volume for the decay through electron-hole pair creation is zero. Note that, this is true only near the Fermi energy where the band structure can be approximated by Dirac cones. For the photo-holes at higher binding energies, the available phase space volume becomes non-zero. This fact was previously pointed out by *Moos et al.*<sup>3</sup> If we limit our discussion to the low energy dynamics in graphite, the effect of the electron-electron interaction can be neglected.

### C. Other scattering mechanisms

There are other mechanisms in graphite that may contribute to the quasi-particle scattering such as plasmons, impurities and defects. *Xu et al.* suggested that plasmons may be the main source for the quasi-particle scattering in graphite<sup>2</sup>. However, *Spataru et al.* showed that electron-hole pair creation should be a more dominant mechanism than electron-plasmon interactions for electron scattering in graphite<sup>5</sup>. Since we have shown in our earlier work<sup>14</sup> that electron-phonon interaction is more dominant than electron-hole pair creation based on a phase space argument, we may conclude that electron-plasmon interaction is much weaker than electron-phonon coupling and thus may be neglected. Impurity and defect scattering can also contribute to the scattering rate in graphite. These scattering mechanisms also have a rate that is proportional to the electronic DOS as in the electron-phonon coupling case and thus increase the slope for the imaginary part of the self energy. This fact tells us that, if one wants to study the electron-phonon coupling, the experiment should be conducted on clean single crystalline graphite. In our case, we used natural graphite single crystals which have superior quality to crystals used in other experiments. As a results, we did not observe any defect related states<sup>13,34</sup> and we therefore believe that defect or impurity scattering is minimal.

In short electron-phonon coupling should be mechanism, other mechanisms are suppressed due to lack of phase space (electron-hole pair) or high quality of the crystal (low impurity/defect levels).

## III. EXPERIMENT

ARPES experiments were performed at Beamline 7.0.1 of the Advanced Light Source. We used very high quality natural graphite single crystals with sizes larger than  $\approx 1$  cm. Samples were cleaved repeatedly *ex situ* by tap-

ing method until a flat surface without large flakes were obtained. Samples were subsequently introduced to the ultra high vacuum chamber and annealed at 900°C for 30 minutes in a vacuum better than  $6.0 \times 10^{-10}$  Torr. to clean the surface. The energy resolution was  $\approx 40$  meV. The chamber pressure was better than  $5.0 \times 10^{-11}$  Torr. during the measurements. We found that typical size of the flat regions without flakes was smaller than 200  $\mu\text{m}$ . Therefore, we exploited the small beam spot ( $\approx 50$   $\mu\text{m}$ ) to probe flat region.

We took  $k_z = H$  data at 20K with a photon energy of 103.4 eV to obtain the electron-phonon coupling by analyzing the peak width as a function of the binding energy. This is essentially the same as what we reported earlier<sup>14</sup> but at the  $H$  point. In addition, we performed temperature dependent experiment at the  $K$  point with a photon energy of 85 eV. ARPES data was taken at 25K, 75K, 125K, 175K, 225K. We started measuring at 225K and lowered the temperature. After having measured at 25K, we annealed the sample again for  $\approx 30$  seconds, at  $\approx 900^\circ\text{C}$  and measured again. Comparison of the data before and after annealing showed essentially no difference, indicating there was no surface contamination during the measurement. For comparison, graphene data were also taken at the  $K$  point. The graphene sample was epitaxially grown on 6H-SiC *in situ* as reported elsewhere<sup>39</sup>. Electronic band structure calculation was done by using the SIESTA code based on pseudo-potential method.

## IV. RESULTS AND DISCUSSION

### A. Low temperature case

Fig. 4(a) shows measured ARPES spectral function along the  $L-H-A$  symmetry line. The non-bonding band (NB) and bonding band (BB) are degenerate at the  $H$  point whereas they are split at  $K$  point. We could identify only one peak in the energy (EDCs) and momentum (MDCs) distribution curves. We also took data with different photon energies, to insure that we were really at the  $H$  point. The electronic band near the Fermi energy shows a linear dispersion as predicted in the band calculation in Fig 1.(c). However, we also note that the band dispersion very near the Fermi level shows some parabolic component contrary to what is expected from the theory. This could be due to  $k_z$  broadening caused by the finite escape depth. We also note that there are no evidence defect-induced states that were reported earlier<sup>32</sup>. This indicates that our natural graphite single crystals are of very high quality. Almost, the negligible background of our data even at high binding energy further supports the high quality of our sample. This means that defect or impurity contribution to the scattering rate is very small and we may only consider the electron-phonon coupling effect.

Fig. 4(b) shows the EDC from the  $k$  point indicated by the arrow in panel (a). The line shape of the EDC

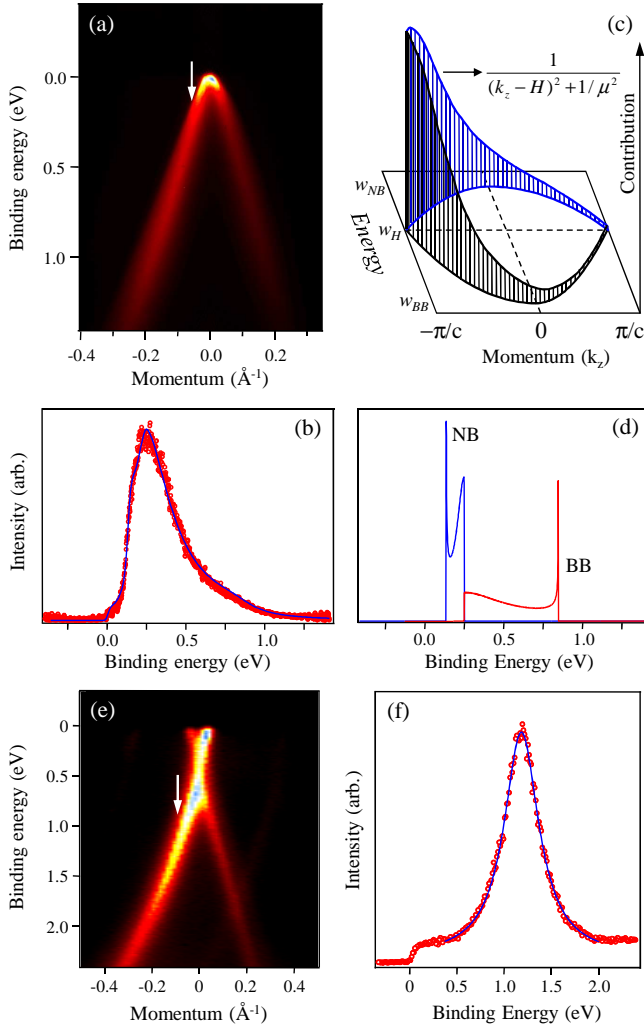


FIG. 4: (a) ARPES data taken at H point of graphite along  $L$ - $H$ - $A$  direction. (b) The EDC at the  $k$  point marked the arrow in panel (a). Circles are the experimental data and thick line is the fit for which finite escape depth effect in photoemission process has been considered (see the text). (c) Contributions from different  $k_z$  points due to the finite escape depth effect. (d) The model fitting function with finite escape effect considered but without lifetime effect. (e) ARPES data at  $K$  from epitaxially grown graphene on 6H-SiC. (f) The EDC (at the  $k$  point marked by the arrow in panel (e)) shows symmetric lineshape unlike that from graphite. The EDCs can be fitted with a single Lorentzian and constant background (thick line).

is very asymmetric. As was the case for the  $K$  data<sup>14</sup>, we can understand this asymmetry as follows. Though we tuned the photon energy to probe the  $H$  point of graphite, the finite escape depth of the photoelectron yields an uncertainty in  $k_z$ ,  $\Delta k_z = 1/\mu$  where  $\mu$  is the escape depth. Therefore, there is contribution from other  $k_z$  values which is illustrated in Fig. 4(c). As the BB and NB have finite  $k_z$  dispersions, the contribution from other  $k_z$  values results in broadening of the spectral function. The fact that the BB has more  $k_z$  dispersion gives

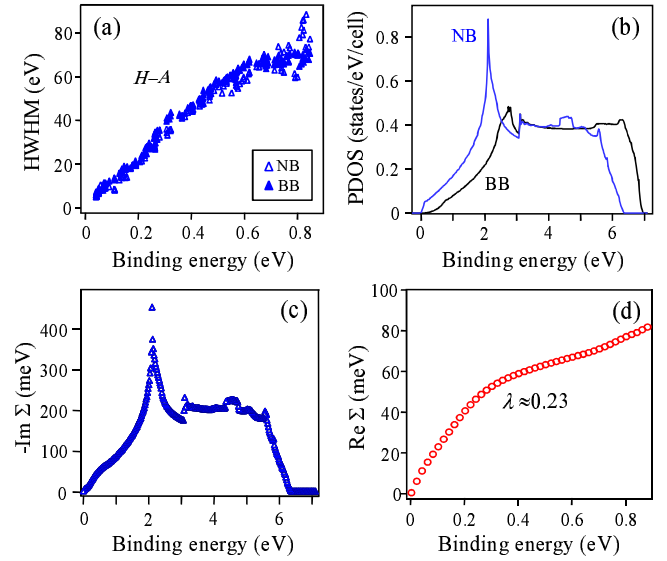


FIG. 5: (a) Extracted HWHM as a function of the binding energy for NB (triangles) and BB (filled triangles). (b) Calculated pDOS for NB and BB (c) Constructed  $\Sigma''$  from the data in panel (a) for the low energy region and pDOS in panel (b). pDOS is scaled so that it matches the experimental HWHM at 0.9 eV. (d)  $\Sigma'$  using Hilbert transform of  $\Sigma''$ . The EPC parameter is  $\approx 0.23$ .

more broadening on the higher binding energy side as seen in Fig. 4(b).

Fig. 4(d) depicts a model spectral function when all these effects are accounted for. Only when such effects are considered, can one extract the true lifetime broadening. We used  $\mu = 7\text{\AA}$  for the fitting<sup>40</sup>, and the model function in Fig. 4(d) is convolved with a Fermi function and a Voigt function with the Gaussian width set to the total energy resolution of 40 meV. In addition, we introduced binding energy dependent Lorentzian width for the Voigt function considering the observation from the  $K$  data that the Lorentzian width linearly increases as a function of binding energy<sup>14</sup>.

Even though this  $k_z$  uncertainty is a general property of ARPES measurement, perfect 2D material such as graphene should not show this escape depth effect in their ARPES data because it has no dispersion in the  $k_z$  direction. To ensure that the asymmetric line shape in graphite is indeed from the finite escape depth effect, we took graphene ARPES data and check if the line shape is symmetric as expected. Fig. 4(e) shows ARPES data along the  $M$ - $K$ - $\Gamma$  direction of graphene which was epitaxially grown on 6H-SiC. Fig. 4(f) is an EDC curve from the  $k$  point arrow marked in panel (e). The EDC shows very symmetric line shape contrary to the EDC in panel (b). One can fit this curve with a single Lorentzian with constant background as shown with the thick line in Fig. 4(f). An almost perfect fit strongly supports the idea that the asymmetric line shape of graphite data is indeed from the finite escape depth effect.

Fig. 5(a) shows the half width at half maximum

(HWHM) found by fitting our model to the EDCs along the high symmetry line  $H-A$ . Filled and empty symbols represent BB and NB widths, respectively. There is almost no difference between the BB and NB widths. The width increases linearly as a function of the binding energy. We find that the width shows no high order dependence such as  $\sim \omega^2$ . This also indicates that the EPC is the dominant decay channel in graphite as expected from our model. Yet, observation of very weak or no kinky feature at the optical phonon energy of 0.2 eV shows that EPC is very weak in graphite. On the other hand, the width converges to zero as the binding energy goes to zero, which means that momentum mixing due to impurity or defects is minimal, supporting again the high quality of the samples.

One can extract the EPC parameter from the derivative of  $\Sigma'$  at  $\omega=0$ . Conventionally, one obtains the  $\Sigma'$  from the difference between the experimental dispersion and the bare band. In graphite, this is a difficult task because the bare band may not be linear. On the other hand, even though harder, one can get  $\Sigma'$  by Hilbert transforming  $\Sigma''$ . To do the Hilbert transformation, we need to know  $\Sigma''$  over the entire energy range. As this is not the case, we use scaled partial electronic DOS (pDOS) as  $\Sigma''$ , assuming that  $\Sigma''$  is approximately proportional to pDOS<sup>14</sup>. Fig. 5(b) shows pDOS of NB and BB. Fig. 5(c) is the  $\Sigma''$  for NB band, obtained from the experimental data and calculated pDOS for NB. Hilbert transform of it gives the  $\Sigma'$  shown in Fig. 5(d). According to Eqn. (5), we can find the electron phonon coupling parameter from the energy derivative of  $\Sigma'$  at  $\omega = 0$ . The resulting value is  $\lambda \approx 0.23$ , very similar to the value of  $\lambda = 0.2$  for the  $K$ - $\Gamma$  direction reported in our previous work<sup>14</sup>. This value is larger than the calculated value of 0.075 for graphene<sup>7</sup> but much smaller than the previously reported value for graphite<sup>13</sup>. In addition, this value is consistent with the value of 0.21 calculated with a reasonable scattering amplitude  $g$ <sup>9</sup>. Therefore, we conclude that EPC constant  $\lambda$  is also small at the  $H$  point.

## B. Finite temperature case

Fig. 6 shows temperature dependence ARPES data at  $K$  point of graphite, which were taken at 225, 175, 125, 75, and 25K. One can clearly distinguish the NB from the BB in each panel. Note that the binding energy difference between the NB and the BB is about 0.8 eV. Overall, the data do not appear to show much temperature dependence. To see this quantitatively, we performed the same lineshape analysis we developed on the data. Every EDC from -0.2 to 0 Å of each panel in Fig. 6 is fitted with our model function and HWHM is extracted.

Extracted HWHM vs. binding energy at different temperature is plotted in Fig. 7. Overall, HWHMs linearly increase proportional to binding energy. All HWHMs are quite similar to each other and one can safely say that there is no clear temperature evolution of spectral

function. This already indicates that the energy of the phonon mode which is involved in electron-phonon coupling in graphite is very high compared to the temperature scale of our measurement 225K.

Calculated imaginary part of self-energy is used to fit the extracted HWHM of the 25K data (Fig. 8(a)). In fitting the data, we assumed an Einstein phonon of  $\omega_0 = 200$  meV. The imaginary part is supplemented with a constant plus an energy-dependent term  $\Sigma_{ee} = A\omega^2$  in order to simulate the electron-electron interactions. The partial DOS of the NB band were calculated from the LDA calculation. The coupling amplitude  $g$  is a fitting parameter. We find that  $g$  is  $\approx 0.39$  eV and electron-electron interaction pre-factor is  $\approx 0.004$ . Note that negligible electron-electron interaction near the Fermi energy is confirmed as predicted earlier in our model.

With the fit result, one may try to evaluate the electron-phonon coupling constant  $\lambda$  from the  $g$  value. By Hilbert transforming the model fit function of  $\Sigma''$ , we obtain  $\Sigma'$ . Derivative of  $\Sigma'$  at  $\omega = 0$  as in Eqn. (4) gives us  $\lambda$  of  $\approx 0.14$ . This value is smaller than the value of  $\lambda = 0.2$  at  $K$  which was obtained from the experimental data<sup>14</sup>. A key difference between the two methods is that while we assume an Einstein phonon of  $\omega = 200$  meV, no such assumption is used in transforming the experimental data. However, the experimental data is more susceptible to systematic errors, especially at very low binding energy range (where the line shape is affected by Fermi function). Since the low energy range has more effect on  $\lambda$  and a theoretical result shows  $\omega = 200$  meV is the dominant phonon<sup>7</sup>,  $\lambda = 0.2$  probably gives us the upper bound for the electron-phonon coupling.

Other panels in Fig. 8 show HWHMs and fitted model function at different temperatures. The fitting was conducted on NB bands along  $M-K$  near the Fermi energy at each temperature. As could already been seen in Fig. 7, fitting of the HWHM results in negligible temperature dependence. This indicates that the phonon involved in the coupling has much higher energy scale than 225K. In fact, the 200 meV bond-stretching mode may be the most dominant one as the *ab initio* calculation on graphene shows<sup>7</sup>.

## V. CONCLUSION

We present high resolution ARPES data taken at the  $H$  point of natural graphite single crystals. The graphite bands shows a linear dispersion as predicted in LDA calculation and the NB and BB are degenerate. First, we considered various scattering mechanisms in graphite. We deduced theoretical formula for the scattering rate by phonons. We find that the scattering rate by EPC increases linearly with binding energy due to the linear density of states. Electron-electron interactions in graphite are negligible in the low binding energy region where the band dispersion is linear. The impurity or defect scattering rate is also proportional to binding energy because of

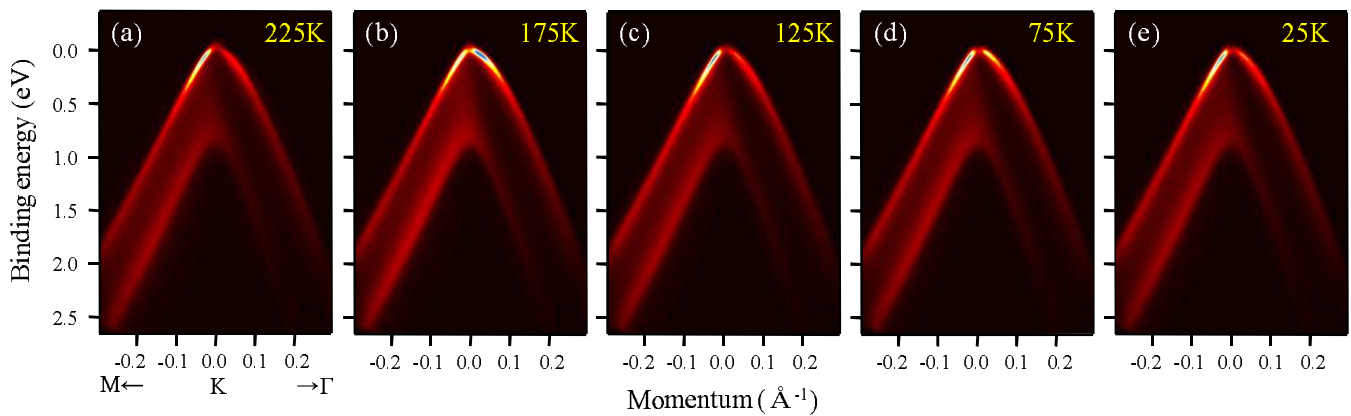


FIG. 6: ARPES data taken along  $M - K - \Gamma$  at different temperatures. (a),(b),(c),(d), and (e) were taken at 225K, 175K, 125K, 75K, and 25K, respectively.

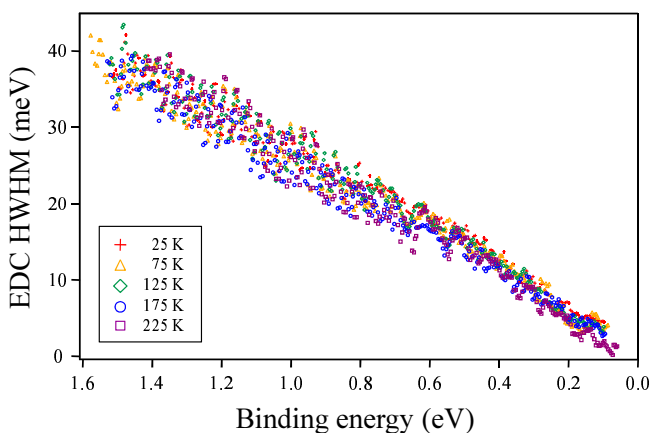


FIG. 7: HWHM vs. binding energy at different temperatures, 25, 75, 125, 175, and 225K. HWHM is extracted from NB band along  $M$ - $K$  near Fermi energy.

linear DOS. We show that all effects other than phonon scattering are negligible. Second, with the finite escape depth effect in photoemission process considered, we extracted  $\Sigma''$  from the EDCs of the NB and BB separately. Finally, we approximated  $\Sigma''$  by combining the experimental HWHM  $\Sigma''$  and calculated partial DOS. The obtained  $\Sigma''$  is converted to  $\Sigma'$  through a Hilbert transform. The extracted EPC parameter at  $H$  is  $\approx 0.23$ , which is small, consistent with the value 0.2 from the K point in our previous work. This small EPC parameter is also consistent with very weak kinky features in our data.

In addition, we conducted temperature dependent ARPES measurements on the graphite K point. The temperature dependent data shows no notable evolution in the EDC lineshape within the temperature range (25-225K). Analyzing the experimental temperature dependence of peak widths and simulated temperature dependence, we conclude that the dominant phonon mode in EPC in graphite is much larger than the temperature scale of our experiment 225K. This is consistent with the

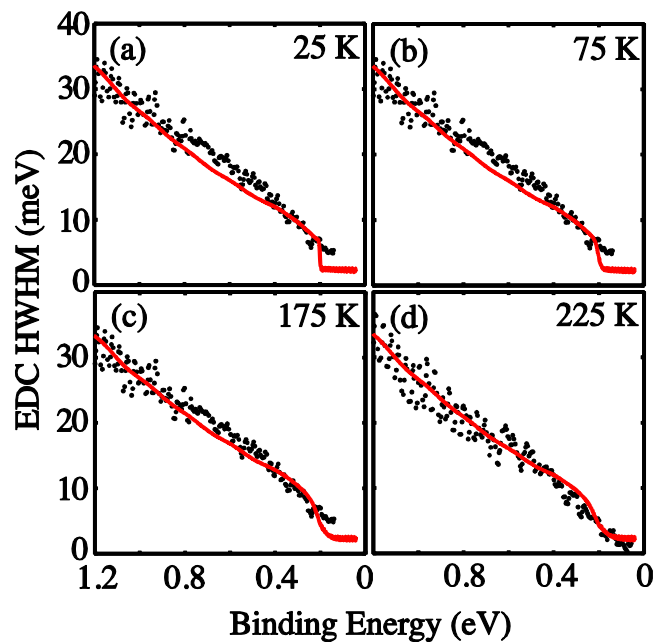


FIG. 8: HWHMs extracted from ARPES data at different temperatures are fitted by calculated imaginary part of self-energy. Panel (a),(b),(c) and (d) are for temperatures of 25, 75, 125 and 175K, respectively. The solid line in each panel is the best fit to the experimental data by calculated imaginary part of self-energy. The calculated imaginary part of self-energy includes electron-phonon and electron-electron interaction terms. The electron-phonon coupling constant and electron-electron interaction pre-factor were used as fitting parameters (see the text).

notion that the phonon mode in electron-phonon coupling in graphite is the 200 meV optical phonon mode as is the case for graphene.

Even though electron-phonon coupling has been heavily studied, most of these studies were focused on metallic systems where the density of states near the fermi level is approximately constant. Such is not generally true, es-



pecially for semi-metals. The formulas discussed in this work are very general and can be used for any shape of electronic density of states. It should therefore be useful in the future studies on semi-metals.

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